

Polar3[™] HiperFET[™] **Power MOSFET**

IXFT94N30P3 IXFQ94N30P3 IXFH94N30P3

6.0

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Rectifier

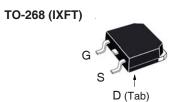


	PD	
G -		
	\(\sigma_s\)	

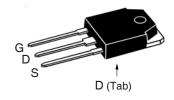
Symbol	Test Conditions	Maximum R	atings
V _{DSS}	$T_{_{\rm J}}$ = 25°C to 150°C	300	V
V _{DGR}	$T_J = 25^{\circ}\text{C} \text{ to } 150^{\circ}\text{C}, R_{GS} = 1\text{M}\Omega$	300	V
V_{gss}	Continuous	± 20	V
V _{GSM}	Transient	± 30	V
I _{D25}	$T_c = 25^{\circ}C$	94	А
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	235	Α
I _A	$T_c = 25^{\circ}C$	47	Α
E _{AS}	$T_{c} = 25^{\circ}C$	2.5	J
dv/dt	$I_{_{\mathrm{S}}} \le I_{_{\mathrm{DM}}}, V_{_{\mathrm{DD}}} \le V_{_{\mathrm{DSS}}}, T_{_{\mathrm{J}}} \le 150^{\circ}\mathrm{C}$	35	V/ns
P_{D}	T _C = 25°C	1040	W
T		-55 +150	°C
T _{JM}		150	°C
T _{stg}		-55 +150	°C
T _L	Maximum Lead Temperature for Soldering	300	°C
T _{SOLD}	Plastic Body for 10s	260	°C
M _d	Mounting Torque (TO-247 & TO-3P)	1.13 / 10	Nm/lb.in
Weight	TO-268	4.0	9
	TO-3P	5.5	g

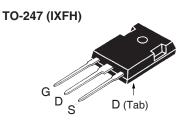
Symbol (T _J = 25°C U	Test Conditions Unless Otherwise Specified)	Charac Min.	teristic Typ.		
BV _{DSS}	$V_{gs} = 0V, I_{D} = 1mA$	300			V
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 4mA$	3.0		5.0	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$			25	μΑ
	$T_J = 125$ °C			750	μΑ
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$			36	mΩ

= 300V**94A** D25 $36m\Omega$ $\boldsymbol{R}_{\text{DS(on)}}$



TO-3P (IXFQ)





G = Gate D = Drain S = SourceTab = Drain

Features

- Fast Intrinsic Rectifier
- Avalanche Rated
- $^{\bullet}$ Low $\rm R_{\rm DS(ON)}$ and $\rm Q_{\rm G}$
- Low Package Inductance

Advantages

g

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls

TO-3P TO-247



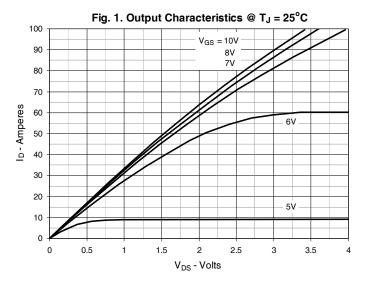
Symbol	Test Conditions	Char	acteristic	Values
$(T_J = 25^{\circ}C \text{ Ur})$	nless Otherwise Specified)	Min.	Тур.	Max.
g _{fs}	$V_{DS} = 20V, I_{D} = 0.5 \bullet I_{D25}, Note 1$	40	68	S
C _{iss}			5510	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		965	pF
C _{rss}			25	pF
\mathbf{R}_{Gi}	Gate Input Resistance		1.2	Ω
t _{d(on)}			23	ns
t _r	Resistive Switching Times		19	ns
t _{d(off)}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		49	ns
t,	$R_{G} = 1\Omega$ (External)		11	ns
$Q_{g(on)}$			102	nC
Q _{gs}	$V_{\rm GS} = 10 {\rm V}, V_{\rm DS} = 0.5 \bullet V_{\rm DSS}, {\rm I}_{\rm D} = 0.5 \bullet {\rm I}_{\rm D25}$		33	nC
Q_{gd}			37	nC
R _{thJC}				0.12 °C/W
R _{thCS}	(TO-247 & TO-3P)		0.25	°C/W

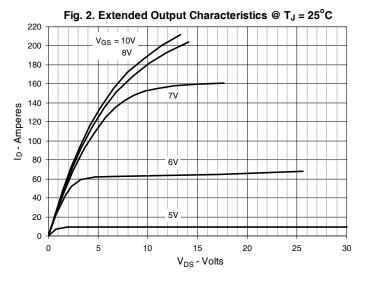
Source-Drain Diode

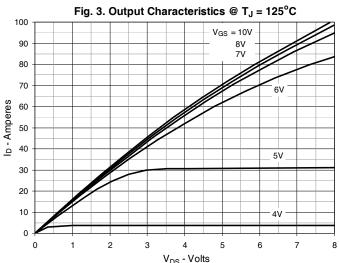
SymbolTest ConditionsChart $(T_J = 25^{\circ}\text{C Unless Otherwise Specified})$ Min.			racteristic Typ.	Values Max.	
I _s	$V_{GS} = 0V$			94	Α
I _{SM}	Repetitive, Pulse Width Limited by $T_{_{\rm JM}}$			376	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.5	V
t _{rr}	$I_{\rm F} = 47A$, -di/dt = 100A/ μ s			250	ns
I _{RM}	$V_{R} = 100V, V_{GS} = 0V$		15.6		Α
Q_{RM}	$v_{R} = 100V, v_{GS} = 0V$		1.4		μC

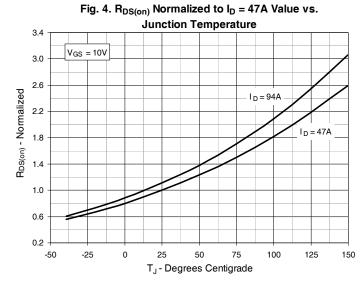
1. Pulse test, $t \le 300 \mu s$, duty cycle, $d \le 2\%$. Note

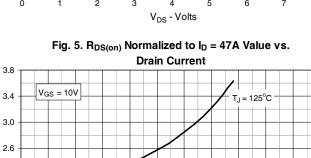






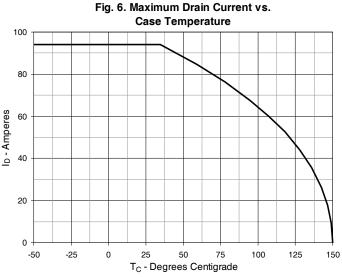






 $T_J = 25^{\circ}C$

180 200 220



60

80

100 120

I_D - Amperes

140

160

RDS(on) - Normalized

1.8 1.4

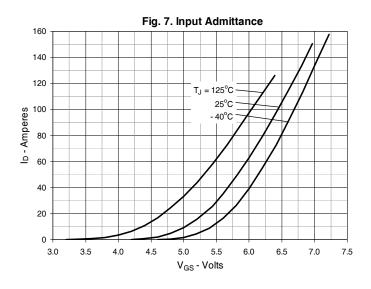
1.0

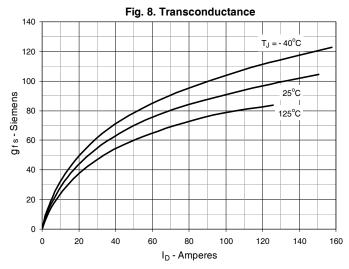
0

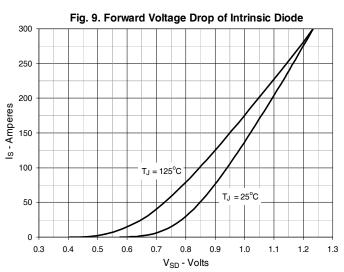
20

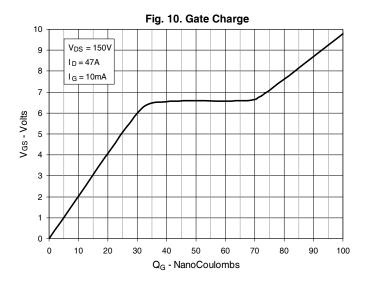
40

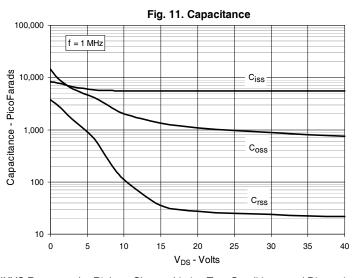


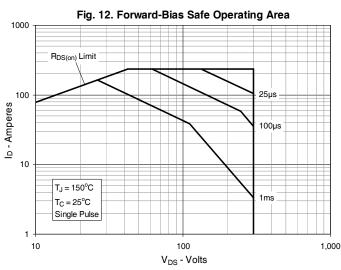






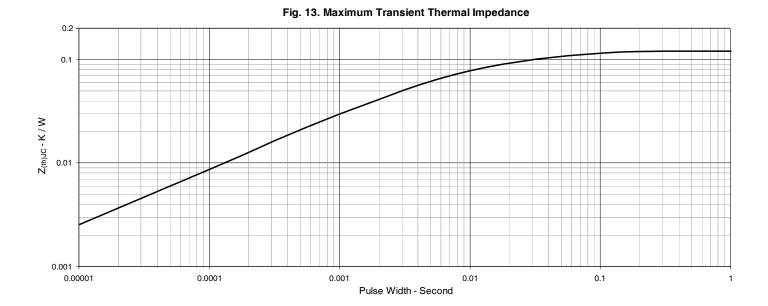






 $\ensuremath{\mathsf{IXYS}}$ Reserves the Right to Change Limits, Test Conditions, and Dimensions.

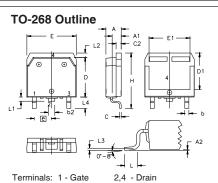




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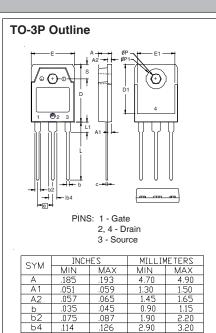


IXFT94N30P3 IXFQ94N30P3 **IXFH94N30P3**



Terminals: 1 - Gate 3 - Source

SYM	INCH	IES	MILLIN	1ETERS
2 1 M	MIN	MAX	MIN	MAX
Α	.193	.201	4.90	5.10
A1	.106	.114	2.70	2.90
A2	.001	.010	0.02	0.25
Ь	.045	.057	1.15	1.45
b2	.075	.083	1.90	2.10
С	.016	.026	0.40	0.65
C2	.057	.063	1.45	1.60
D	.543	.551	13.80	14.00
D1	.488	.500	12.40	12.70
E	.624	.632	15.85	16.05
E 1	.524	.535	13.30	13.60
е	.215	BSC 5.45 BSC		BSC
Н	.736	.752	18.70	19.10
L	.094	.106	2.40	2.70
L 1	.047	.055	1.20	1.40



19.80

3.40 3.20 6.90 4.90

3.60 3.40 7.10 5.10

.142 .134 .280 .201

ØΡ øP1

TO-247	TO-247 Outline				
A1	B 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	2 3 ixy	PINS: 1	- Gate 4 - Drain - Source	
	INCH	IE C	MILLI	METERS	
SYM	MIN	MAX	MIN	MAX	
A	.190	.205	4.83	5.21	
A1	.090	.100	2.29	2.54	
A2	.075	.085	1.91	2.16	
Ь	.045	.055	1.14	1.40	
b2	.075	.087	1.91	2.20	
b4	.115	.126	2.92	3.20	
С	.024	.031	0.61	0.80	
D	.819	.840	20.80	21.34	
D1	.650	.690	16.51	17.53	
D2	.035	.050	0.89	1.27	
E	.620	.635	15.75	16.13	
E1	.545	.565	13.84	14.35	
е	.215	BSC	5.45		
J		.010		0.25	
K		.025		0.64	
L	.780	.810	19.81	20.57	
L1	.150	.170	3.81	4.32	
ØΡ	.140	.144	3.55	3.65	
øP1	.275	.290	6.99	7.37	
Q	.220	.244	5.59	6.20	
R	.170	.190	4.32	4.83	
S	.242	BSC	6.15	BSC	

